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NXP Semiconductors/Freescale Semiconductor, Inc. 1PS70SB16,115

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1PS70SB16

Dual Schottky barrier diode

Product data sheet

1. General description

Dual Planar Schottky barrier diode in common anode configuration with an integrated guard ring for stress protection, encapsulated in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified

3. Applications

- Ultra high-speed switching
- Line termination
- Voltage clamping
- Reverse polarity protection

4. Quick reference data

uick reference data						
Parameter	Conditions		Min	Тур	Мах	Unit
						_
forward current			-	-	200	mA
reverse voltage			-	-	30	V
forward voltage	I _F = 10 mA; T _{amb} = 25 °C		-	-	400	mV
	Parameter forward current reverse voltage	Parameter Conditions forward current	Parameter Conditions forward current	Parameter Conditions Min forward current - reverse voltage -	Parameter Conditions Min Typ forward current - - - reverse voltage - - -	Parameter Conditions Min Typ Max forward current - - 200 reverse voltage - - 30







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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K1	cathode (diode 1)	3	A1, A2
2	K2	cathode (diode 2)		
3	A1, A2	common anode	1 <u>□</u> 2 SC-70 (SOT323)	aaa-004974
			30-70 (301323)	

6. Ordering information

Table 3. Ordering information					
Type number Package					
	Name	Description	Version		
1PS70SB16	SC-70	plastic surface-mounted package; 3 leads	SOT323		

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
1PS70SB16	7%6

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
Per diode		·			
V _R	reverse voltage		-	30	V
l _F	forward current		-	200	mA
I _{FRM}	repetitive peak forward current	t _p ≤ 1 s; δ ≤ 0.5	-	300	mA
I _{FSM}	non-repetitive peak forward current	t_p < 10 ms; $T_{j(init)}$ = 25 °C	-	600	mA
P _{tot}	total power dissipation	T _{amb} < 25 °C	-	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	150	°C



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Symbol	Parameter	Conditions	Min	Max	Unit
T _{stg}	storage temperature		-65	150	°C

9. Thermal characteristics

Table 6. T	hermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per device			· · ·				
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V _F	forward voltage	I _F = 0.1 mA; T _{amb} = 25 °C	-	-	240	mV
		I_F = 1 mA; T_{amb} = 25 °C	-	-	320	mV
		I _F = 10 mA; T _{amb} = 25 °C	-	-	400	mV
		I _F = 30 mA; T _{amb} = 25 °C	-	-	500	mV
		I _F = 100 mA; T _{amb} = 25 °C	-	-	800	mV
I _R	reverse current	V_R = 25 V; pulsed; t _p = 300 μs; δ = 0.02 ; T _{amb} = 25 °C	-	-	2	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _{amb} = 25 °C	-	-	10	pF

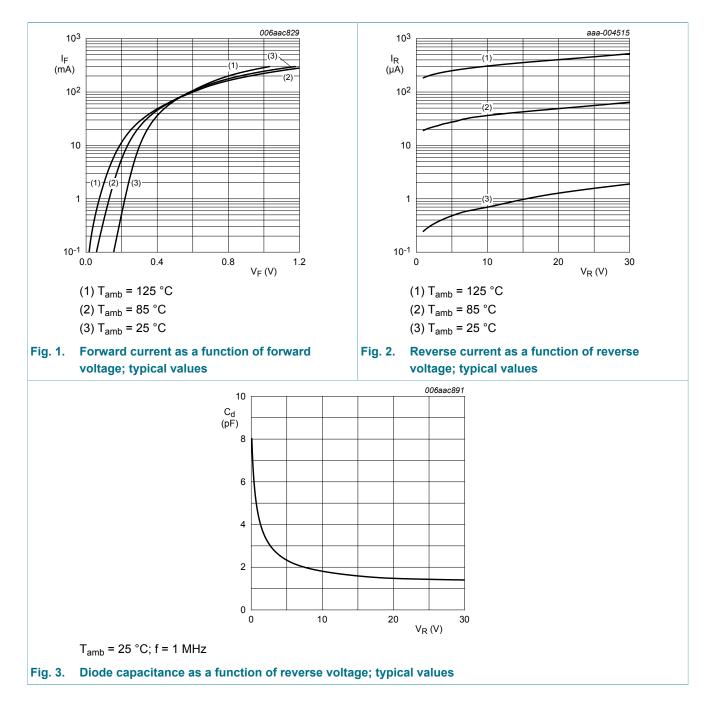
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11. Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

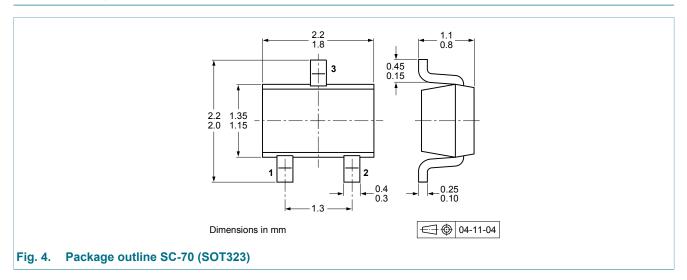


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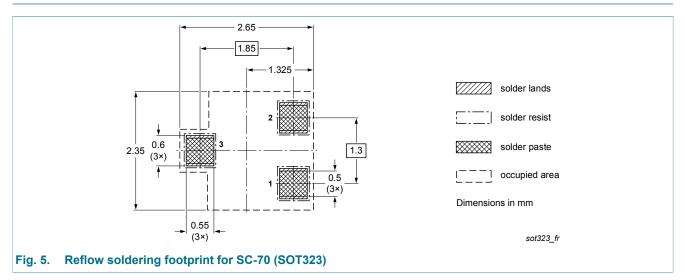
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12. Package outline



13. Soldering

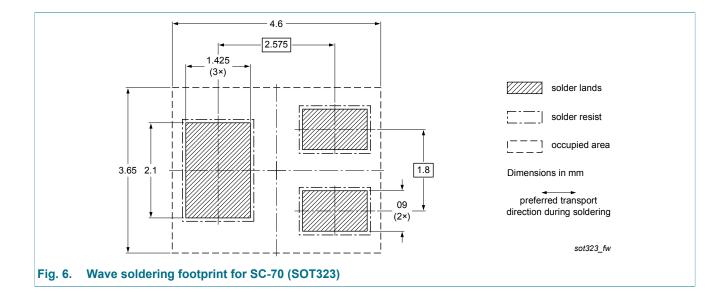




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14. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
1PS70SB16 v.2	20121217	Product data sheet	-	1PS70SB10_14_15_16 v.1
Modifications:	of NXP Semiconduc Legal texts have be Sections 1 to 3 upda Section 4 "Quick ref Section 6 "Ordering Section 7 "Marking" Table 5 "Limiting va Figues 1, 2 and 3 up Section 11 "Test info	ctors. en adapted to the new co ated ference data" added information" added updated lues": ambient temperatu pdated prmation" added ed by minimized package ng" added	igned to comply with the ompany name where app and junction tem outline drawing	ropriate.
1PS70SB10_14_15_16 v.1	19990426	Product data sheet	-	-



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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- The term 'short data sheet' is explained in section "Definitions". [2]
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